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Hematite coated, conductive Y doped ZnO nanorods for high efficiency solar water splitting

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Abstract

For the first time, hematite (α -Fe₂O₃) crystals were electrochemically deposited over vertically aligned conductive zinc oxide nanorods (NR) to form a specially designed 3D heterostructure with a unique triple layer structure. The structure formed with a thin layer of ZnFe₂O₄ sandwiched between the hematite and the ZnO, which forms a barrier to reduce the back migration of holes. Hence, the charge separation is significantly improved. The small unequal bandgaps of α -Fe₂O₃ and ZnFe₂O₄ help to enhance and broaden visible light absorption. The electron transportation was further improved by yttrium doping in the ZnO (YZnO) NRs, resulting in increased conductivity. This allowed the vertically aligned NRs to perform as electron highways, which also behave as effective optical waveguides for improved light trapping and absorption, since ZnO absorbs little visible light. All these benefits made the unique structures suitable for high performance photoelectrochemical (PEC) water splitting.

Optimisation of α -Fe₂O₃ thickness led to a photocurrent density improvement from 0.66 to 0.95 mA cm⁻² at 1.23 V_{RHE}. This was further improved to 1.59 mA cm⁻² by annealing at 550 °C for 3 h, representing a record-breaking photocurrent for α -Fe₂O₃/ZnO systems. Finally IPCE confirmed the successful generation and transfer of photoelectrons under visible light excitation in the specifically designed heterostructure photoanode, with 5% efficiency for blue light, and 15% for violet light.

Supplementary material for this article is available [online](#)

Keywords: Y doped ZnO nanorods, solar water splitting, hematite coating, optical waveguide

(Some figures may appear in colour only in the online journal)

1. Introduction

Great innovation and radical new solutions are required to meet the threat posed by climate change [1]. Although great progress has been achieved in renewable energy generation,

one of the key factors restricting electrification is energy storage [2]. PEC water splitting provides an elegant solution, harvesting and storing solar energy in chemical H₂ bonds [3–5]. Requiring aqueous insolubility and band edge positions suitable to surmount the over potentials for water redox, metal oxides such as TiO₂ and ZnO have been the focus of much literature for this application [6–9]. Boasting superior electronic properties and the simple solution growth of nanostructures, ZnO has yet to reach its full potential for solar water splitting [10]. The main restriction is its large band gap, 3.2 eV, rendering this material unable to absorb most sunlight,

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although this factor can be negated through the use of doping and coating [11].

This has led to the investigation of many small band gap semiconductors for visible light sensitisation, including CdS [12], MoS₂ [13], WO₃ [14], Ta₃N₅ [15], BiVO₄ [16], g-C₃N₄ [17] and α -Fe₂O₃ [18]. Hematite (α -Fe₂O₃) is an excellent candidate to facilitate the photocatalytic water splitting reaction. It absorbs a greater portion of the solar spectrum with a narrow band gap of 2.1 eV. However, it suffers from poor charge transportation. The room temperature charge mobility for hematite is of the order of $10^{-2} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ [19, 20], compared to $166 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ for ZnO NRs [21]. Hence, its diffusion length of minor charge carriers (holes) is extremely short (2–4 nm) and so is the lifetime of charge carriers (6 ps, ~ 1000 times shorter than TiO₂), resulting in the high probability of electron–hole recombination [22–24]. Meanwhile, hematite also has a relatively low optical absorption coefficient, due to its indirect band gap [25]. A minimum film thickness of 400 nm is needed to absorb 95% of the light at 550 nm [26].

In fact, limited charge mobility and high recombination rate are the common problems for many semiconductors due to partial hybridisation of electronic structures. For hematite, several approaches have been taken to overcome the mobility problem. Firstly, dopants were introduced to modify various aspects of hematite properties selectively [25]. Adding tetravalent cations, such as Si⁴⁺ and Ti⁴⁺, has helped achieve the highest photocatalytic water splitting performances so far [27, 28]. Alternatively, innovations in the design of morphologies also show promise. For example nanostructured hematite, like NRs [29], nanowires [30], cauliflower-like [31], or highly porous films could also address poor minority carrier diffusion [32]. With specific anisotropic nanoscale morphologies, charge recombination can be effectively reduced, resulting in significantly improved photocatalytic performance [33]. However, such unsupported nanostructures with material thickness of 4–5 nm could significantly weaken the mechanical and chemical stability of hematite. Hence, a new composite nanostructure design has been developed to achieve both improved charge mobility as well as short charge diffusion pathways, without sacrificing the stability of the hematite materials. For example, hematite nanocrystals were deposited on conductive nanowires made of Au and Si [34, 35], obtaining structures with conductive cores and hematite shells. However, due to the opaque nature of Au and Si, the light scattering within the nanostructures and light absorption by hematite is highly restricted. This in turn, could limit the photocatalytic performance [34].

Although doping tetravalent cations can improve the overall photocatalytic performance, the approach is specifically effective for hematite [27, 28]. Hence, it is important to develop a universal design that can be applied to any photocatalyst suffering from limited charge mobility and weak light absorption. In this paper, we present a 3D electrode platform based on vertically aligned transparent conductive oxide (TCO) nanorods. The TCO structure is formed with YZnO nanorods (NR) synthesised by rapid microwave assisted chemical deposition [36]. Hematite nanocrystals were

deposited on the TCO NRs to test the enhancement of photocatalytic water splitting performance. In our previous work, Y doping has shown favourable effects due to high conductivity and increased NR aspect ratio [37]. The high conductance of the NRs minimises the energy cost with rapid photoelectron transport [37]. ZnO is transparent in the visible light region, hence the vertically aligned NRs behave as optical waveguides for visible light. The photonic advantages are made clear in figure S1 (available online at stacks.iop.org/NANO/31/265403/mmedia), where simple Fresnel calculations show total internal reflectance above 40° of incident angle from ZnO to aqueous electrolyte. Conversely, light trapped within the ZnO has a finite probability of transmitting into the iron oxide at all incident angles, implying effective light trapping and delivery. With side-emitted light scattered between α -Fe₂O₃ thin films, light illumination and absorption can be significantly improved. As such, only a very thin layer of hematite (8–16 nm) was required to coat the YZnO NRs, allowing a short diffusion distance for minority charge carriers to the electrolyte. By combining α -Fe₂O₃ with TCO, YZnO NRs, the weaknesses of α -Fe₂O₃, including: limited charge mobility; short hole diffusion length; poor light absorption and the mechanical stability of the nanostructured hematite can be effectively overcome. More importantly, this novel design can be generally applied to any semiconductor materials with similar weaknesses.

Furthermore, upon annealing of the sample at 550 °C, a ZnFe₂O₄ layer was formed at the interface between YZnO and α -Fe₂O₃. This material has a favourable band structure with smaller band gap energy relative to YZnO and α -Fe₂O₃. Therefore, a wider range of solar spectrum can be harvested.

In this work we demonstrate the benefits of doping ZnO with yttrium, and the electrochemical deposition and formation of Fe₂O₃ nanoparticles, which increase effective surface area to facilitate rapid evolution of oxygen under visible light excitation. Furthermore, the triple junction of YZnO/ZnFe₂O₄/Fe₂O₃ structure allows efficient charge separation evidenced by electrical impedance spectroscopy (EIS). The structure of the 3D photoanode design, light scattering and absorption, short hole diffusion pathways as well as fast charge transportation are summarised in figure 1. Under optimised conditions, a top performance of 1.59 mA cm^{-2} at $1.23 \text{ V}_{\text{RHE}}$ was achieved, launching the novel nanostructured photoanodes to one of the highest performances in literature. The success of the junction is down to the suppression of electron hole recombination in the iron oxide species, alongside the effective electron transportation and light illumination through the TCO, YZnO NRs.

2. Experimental methods

2.1. Y doped ZnO synthesis

Transparent conducting glass substrates (fluorine doped tin oxide, FTO) of $12 \times 20 \text{ mm}^2$ were cleaned by sonication in a sequence of acetone, isopropanol and DI water for 20 min each. The substrate was seeded using a 0.1 M zinc acetate

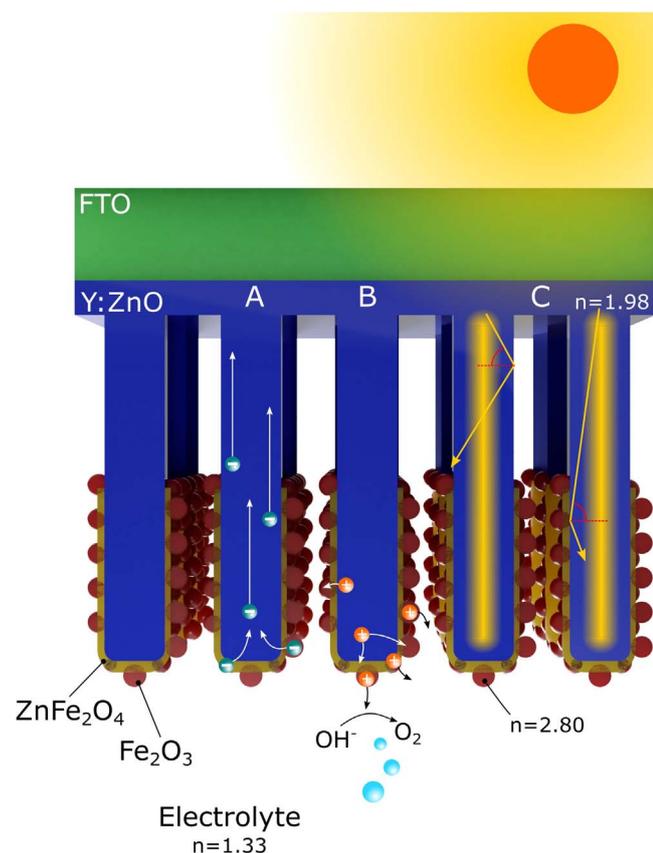


Figure 1. The YZnO/ZnFe₂O₄/Fe₂O₃ triple junction architecture of designed 3D photoanode with key mechanisms affecting the solar water splitting. The mechanisms include A, rapid electron transportation using conductive Y doped ZnO; B, short hole diffusion pathways to electrolyte and C, the visible light waveguiding through light scattering and side emission through ZnO NRs.

solution in DI water with added 0.6 wt% polyvinyl alcohol for viscosity. The solution was spin coated using a two stage programme, 800 RPM for 90 s followed by 30 s at 2000 RPM. This was followed by annealing in air at 500 °C for 20 min to form the zinc oxide seeding layer [38]. The vertically aligned NRs were synthesised using a rapid microwave assisted deposition described in previous work [36]. Briefly, the substrate was placed face down in 20 ml aqueous solution of 40 mM zinc nitrate and hexamethyltetramine (HMT) in 1:1 molar ratio. The sample was heated at microwave power of 100 W to 100 °C for a 30 min holding time [36]. A total of 4 heating cycles were used for each sample. Samples were subsequently annealed in air at 500 °C for 30 min. Yttrium doped samples were produced using 1% molar addition of yttrium nitrate (with respect to zinc nitrate) to the growth solution. The achieved dopant concentration was previously measured to be 0.10 at% by ICP-MS [37].

2.2. Electrochemical deposition of Fe₂O₃

All chemicals were purchased from Sigma Aldrich without further purification. Layers of iron oxide of various thicknesses were formed on the surface of the YZnO NRs by

electrochemical deposition. Firstly an aqueous solution of 0.1 mM FeCl₃ was prepared and transferred to a 100 ml round bottom flask. The YZnO NR on FTO glass sample and a counter electrode of stainless steel foil were inserted into the FeCl₃ solution. The sealed system was then sonicated under vacuum condition to draw out the air between the NRs, shown in figure S2(A). In order to control the deposition rate and film thickness, constant electrochemical potentials were applied at -1.08 , -1.15 , -1.56 and -1.89 V respectively, which offers steady deposition current density of 20, 40, 80 and 120 $\mu\text{A cm}^{-2}$. The typical transient current density behaviour is shown in figure S2(C). The deposition time was fixed for 1 h for all samples. Therefore, the film quality and thickness is controlled by the deposition rate, which is reflected by the deposition current.

After deposition, the samples were dipped in DI water in order to remove any excess solution, followed by annealing at 550 °C for either 30 min, 3 h or 5 h to convert into hematite phase. The substrate post deposition, followed by annealing shows a visible orange colour, shown in figure S2(B). The range of voltages used was significantly higher than found in literature due to the low concentration FeCl₃ solution required to protect the YZnO [39]. The deposition process is summarised in figure 2.

2.3. Structural and physical characterisation

Scanning electron microscopy (SEM, Leica Stereoscan 420) was used to characterise the morphology of the ZnO NRs and their various coatings, INCA software (Oxford Instruments) was used to measure the EDX spectra of the samples. To view the heterojunctions on a nanometre scale, a transmission electron microscope (TEM, JEOL, JEM1400-Plus, at 100 kV) was used, as well as a high resolution TEM (HRTEM, JEOL-3010 at 300 kV). Microscopy images were processed using Image J software (National Institutes of Health, USA). And finally, available crystal phases on the sample were identified using powder x-ray diffraction (XRD, Siemens D500).

2.4. Photoelectrochemical and optoelectronic measurement

For the band gap energy measurement, a UV-vis absorption spectroscopy was used (Lambda 265, PerkinElmer). Photoluminescence (PL) spectroscopy, used to infer recombination rate, was performed with a fluorescence spectrometer (PerkinElmer LS 45). EIS was performed using a three electrode setup, with applied bias across the working photoanode and platinum counter electrode, and a KCl saturated Ag/AgCl reference electrode in a 1 M KOH aqueous electrolyte (pH 13.6). Nyquist plots were measured under illumination at a fixed DC potential (1 V_{RHE}) with a 10 mV AC sinusoidal modulation, at frequencies from 0.1 to 10 000 Hz. A calibrated solar simulator (Oriel LCS-100, Newport) including a built-in AM 1.5G filter with output power of 100 mW cm⁻² was used as the light source. The electrochemical controller used for EIS measurement was Palm Sens 3 (Palm Sens BV) and the results were processed in PSTrace 4.5 (Palm Sens BV). The same system under dark conditions was used to

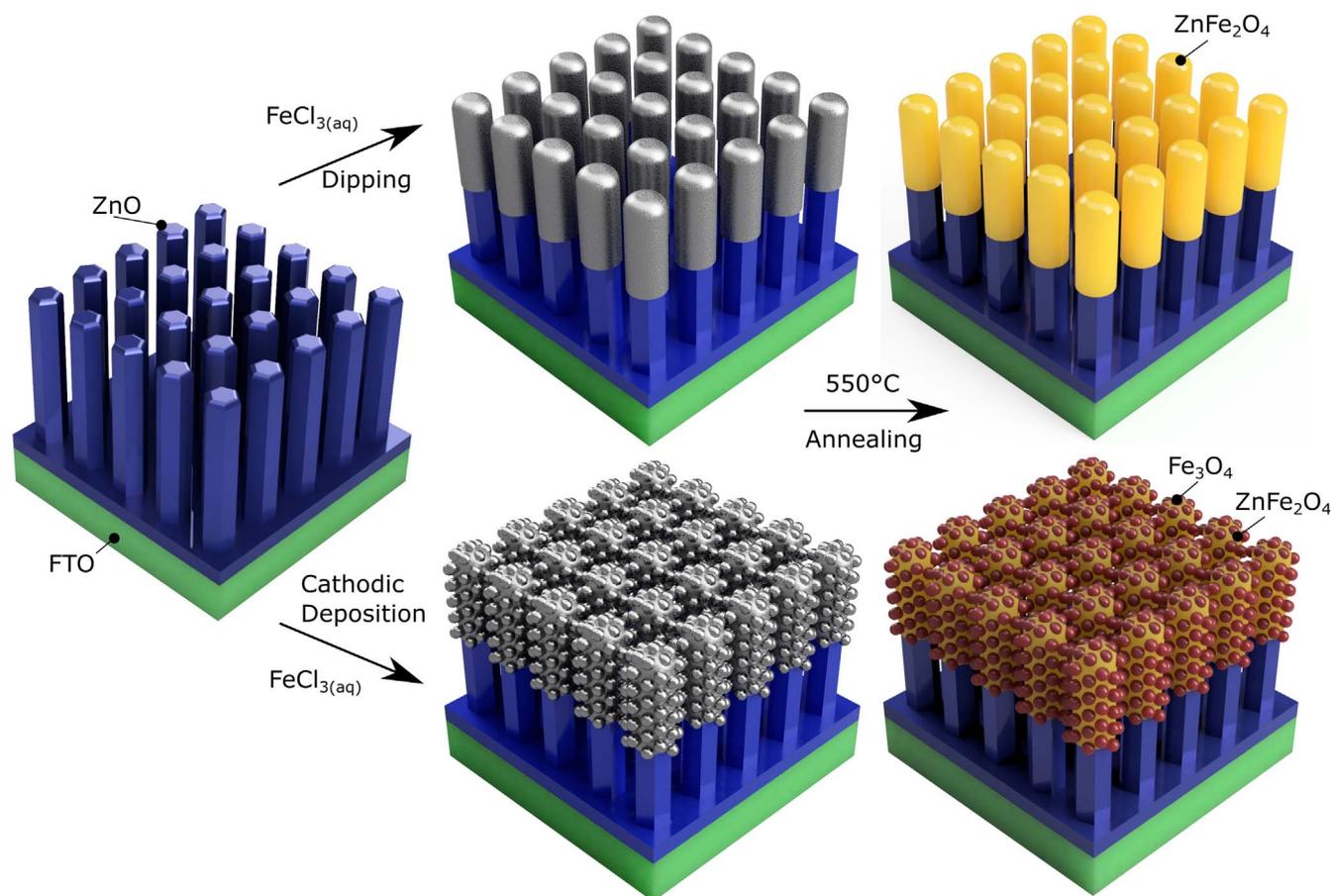


Figure 2. The proposed mechanism of electrochemical deposition steps, including submersion in FeCl_3 solution, reducing current and thermal annealing in air.

measure Mott–Schottky plots at a fixed AC frequency of 1000 Hz, with a DC potential varied from 0 to 1.6 V versus RHE. Surface valence band (VB) measurements were performed using x-ray photoelectron spectroscopy (XPS, Thermo Scientific K-alpha using Al $K\alpha$ source). PEC water splitting was tested using linear sweep voltammetry (LSV). Standard three electrode setup was used with a potentiostat (EA163, eDAQ) scanning in a range from 0 to 1.8 V_{RHE} . Incident photon to current conversion efficiency (IPCE) was measured at 1.23 V_{RHE} with a 300 W xenon lamp coupled with a monochromator. The incident light power was calibrated with a Newport optical power metre and silicon photodiode detector.

3. Results and discussion

3.1. Structural and physical properties

When a cathodic current is applied, $\text{Fe}^{3+}(\text{aq})$ is reduced and deposited at the surface of the ZnO. The substrate changes colour from milky YZnO to a slight yellow tint with a dark grey tone, shown in figure S2(B). Once the sample is annealed at 550 °C, the Fe deposition is oxidised to $\alpha\text{-Fe}_2\text{O}_3$ and the sample colour became more typical light brown.

The morphology of the hematite coated TCO YZnO array was studied by SEM, with a cross sectional image in figure 3(A) and top down images in figure S3. The hexagonal wurtzite ZnO NRs cross section is still visible after deposition at a low current density of $20 \mu\text{A cm}^{-2}$, shown in figure S3(A). The light deposition, confirmed to be surface Fe_2O_3 by EDX (figure S4), was also observed on the surface. The density of the Fe_2O_3 coating was increased with greater deposition current density. At $80 \mu\text{A cm}^{-2}$, figure S3(C), the nanorod structure is overwhelmed, and the channels between the YZnO are filled by cross linked Fe_2O_3 , leading to suppression of surface area. At $120 \mu\text{A cm}^{-2}$, figure S3(D), the surface is completely covered by a connected film of hematite. This film will restrict the infiltration of electrolyte within the NRs and have negative effects on the photocatalytic performance. Thus, it is important to avoid such films while achieving optimum film thickness of the hematite on the NRs. Under our experimental conditions, the optimal hematite morphology was observed at $40 \mu\text{A cm}^{-2}$, shown in figure S3(B). Nanocrystals of $\alpha\text{-Fe}_2\text{O}_3$ are formed which increase surface roughness, beneficial to Faradic charge transfer to the electrolyte. The coated YZnO NRs show some brightened edges which can be associated to the formation of ZnFe_2O_4 at the interface between YZnO and Fe_2O_3 . The top view SEM image in figure S3(A) reveals bright rings on the edge of

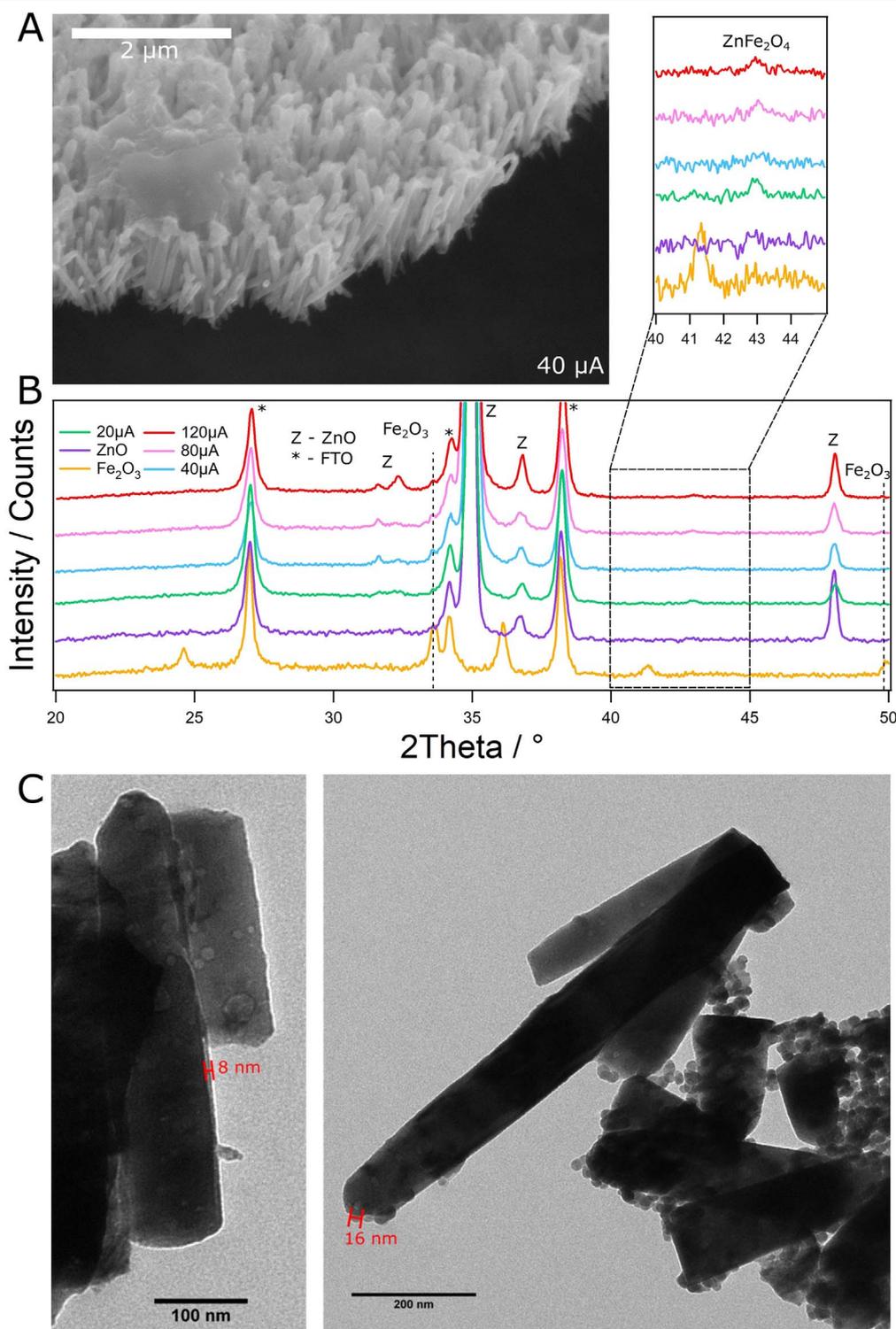


Figure 3. (A) SEM image shows an angled cross sectional image of the $40 \mu\text{A cm}^{-2}$ deposited sample after annealing. (B) Powder XRD curves of various Fe_2O_3 coating thickness, along with pure ZnO and Fe_2O_3 samples, with expanded view of the ZnFe_2O_4 peak occurring at 43°C . TEM images of hematite coated ZnO NRs deposited at $40 \mu\text{A cm}^{-2}$.

YZnO NRs. The formation of ZnFe_2O_4 and its effect on morphology was previously observed by Xu *et al* [40]. The edge brightening is likely due to the ferrimagnetic properties of ZnFe_2O_4 affecting the incoming electron beam [41]. The depth of the coating the overall surface morphology is better viewed in the angled cross sectional SEM of the $40 \mu\text{A cm}^{-2}$

sample, figure 3(A). The aggregates of $\alpha\text{-Fe}_2\text{O}_3$ nanocrystals are visible toward the tips of the wires. The ZnFe_2O_4 is indicated by the bright sleeves coating the YZnO side walls, causing the wires to become thicker away from the base.

Powder XRD was used to confirm the presence of ZnO, ZnFe_2O_4 and $\alpha\text{-Fe}_2\text{O}_3$ on the surface, figure 3(B). XRD of

pure Fe_2O_3 film without ZnO is also displayed as reference. The peaks observed confirm the presence of hematite, $\alpha\text{-Fe}_2\text{O}_3$, with dominant peaks occurring at 24.5° , 33.4° , 36.1° , 40.2° and 49.9° corresponding to crystal planes (012), (104), (110), (113) and (024) respectively (ICDD 01-075-5065). On the Y doped ZnO samples, the strongest (104) peak is seen increased intensity with greater deposition current, from just a shoulder at $20 \mu\text{A cm}^{-2}$, to an obvious broad peak for $120 \mu\text{A cm}^{-2}$. This is the only peak visible from $\alpha\text{-Fe}_2\text{O}_3$ on the coated ZnO NRs due to the relative thin film coating and significant peak overlap with the ZnO and FTO. Meanwhile, ZnO peaks are clearly visible, dominated by the diffraction from the (002) plane at 34.8° , typical for vertically aligned ZnO NRs. Finally, only appearing in samples with both iron and ZnO depositions, a small peak at 43.0° is visible, matching the ZnFe_2O_4 (400) peak (ICDD 22-1012). The peak is visible in all the coated samples, but is most intense for $20 \mu\text{A cm}^{-2}$, likely due to the majority of deposited Fe reacts with Zn to form ZnFe_2O_4 with the least formation of $\alpha\text{-Fe}_2\text{O}_3$.

In order to accurately determine the structure of the triple junction at a nanometre scale, TEM was used to study the coated samples, shown in figure 3(C). A thin layer structure along with nanoparticles is observed coated on the NRs. The 8 nm thickness film directly attached to the ZnO NRs is likely to be the ZnFe_2O_4 . Such a thin layer explains the low intensity of the XRD peak. Connected nanoparticles forming a mesoporous network (right) are likely to be associated with the $\alpha\text{-Fe}_2\text{O}_3$ phase. The particles have an average diameter of 16 nm. This information sheds light on the advantages of electrochemical deposition, firstly there is a good electrical contact between the $\text{YZnO}/\text{ZnFe}_2\text{O}_4$ and $\text{YZnO}/\alpha\text{-Fe}_2\text{O}_3$ interfaces, allowing smooth charge transfer. Secondly the iron phases with typically small minority carrier path length, have small enough domains that charge can reach the surface reaction centres before recombination [42]. Finally the nanoparticle network of $\alpha\text{-Fe}_2\text{O}_3$ allows increased roughness and therefore surface area, than the smooth NRs, promoting high hole transfer rate to the electrolyte.

The structure of the triple junction was more clearly visible under HRTEM, as shown in figure 4. In this case, atomic resolution was obtained for the NRs, nanoparticles and the thin film coating that encased the NRs. Such distinctive morphological features are clearly identified in the zoomed out view of figure 4(A), while figures 4(B)–(D) respectively corresponds to their higher resolution images reviewing lattice constants of each phase. Unsurprisingly, the NR was confirmed as wurtzite zinc oxide with an atomic spacing of 2.45 \AA , the (101) plane spacing, as well as displaying a (002) spot in the FFT of the image in figure 4(B). Figure 4(C) shows the atomic spacing of a spherical nanoparticle, showing high crystal orientation with 4.62 \AA spacing, assigned as $2 \times (006)$ planar spacing of hematite. Finally, figure 4(C) shows wide spacing of 4.88 \AA in the lighter region that forms the full coating around the NR. This is likely to be the 311 plane of ZnFe_2O_4 matching the dominant phase observed by Xu *et al* [40].

In summary hematite nanocrystals were formed together with a thin layer of ZnFe_2O_4 at the interface between YZnO and $\alpha\text{-Fe}_2\text{O}_3$. This novel layered structure formed with three materials utilises the suitability of band edges allowing much improved charge separation and greatly increased visible sunlight water splitting. While highly conductive Y doped ZnO provides rapid transport, $\alpha\text{-Fe}_2\text{O}_3$ yields photoexcited electrons and ZnFe_2O_4 offers an effective electronic barrier blocking the return of electrons from ZnO to the $\alpha\text{-Fe}_2\text{O}_3$.

3.2. Band structure and water splitting performance

With a composite layered semiconductor structure, an internal electrical field can be formed due to the alignment of their valence and conduction bands. This field could improve the charge separation and hence improve the photocatalytic charge efficiency. For PEC water splitting, they must form a junction with suitable band alignment to allow electron transfer away from the solution, and the converse for holes [4].

To determine the band gap energies, E_g , of the junction, UV–vis absorption measurements were applied to pure Fe_2O_3 , YZnO and Fe_2O_3 coated YZnO samples (coated at $40 \mu\text{A cm}^{-2}$). Tauc plots are shown in figure 5(A) [31]. The UV–vis absorption spectra of all coated samples are displayed in the supplemental information in figures S5(A) and (B). Assuredly, the pure Fe_2O_3 sample and the YZnO yielded E_g values of 2.11 and 3.18 eV respectively, typical of these metal oxides. It is worth noting that the Y doped sample displayed a red shift compared to the pristine ZnO prepared by the same method, due to the doping forming new electronic states, outlined in greater detail in our previous work [43]. These results also show that the iron deposition has successfully sensitised the YZnO to visible light, allowing the generation of photoexcited electrons using a far greater portion of the solar spectrum. Electronic transitions from both ZnO and hematite are visible for the $\alpha\text{-Fe}_2\text{O}_3$ coated YZnO NRs, but significantly shifted. The 2.11 eV gap associated with $\alpha\text{-Fe}_2\text{O}_3$ gained a blue shift to 2.34 eV, and the YZnO experienced a red shift to 3.05 eV. This is likely due to two simultaneous doping effects caused by mobile zinc and iron ion migration from sustained 550°C heating. Firstly, Fe^{3+} introduced into the zinc oxide lattice has been previously shown to decrease the electronic band gap [44]. Secondly, Zn^{2+} is a known p-type dopant for hematite [45], this could impart new impurity states below the Fe_2O_3 VB causing the blue shift. Finally, no discernible band gap could be determined for ZnFe_2O_4 therefore the value was taken from literature as 2.1 eV [46].

In order to determine electronic properties, electrochemical impedance spectroscopy was used to determine key parameters. The electronic band configuration can be determined using the Mott–Schottky relation applied to EIS data taken in dark conditions, displayed in figure 5(B). Measurements were taken at a fixed frequency of 1 kHz and a voltage scanned from -0.4 to $1.6 \text{ V}_{\text{RHE}}$ at 0.05 V intervals. The capacitance is modelled with a simple Randle's circuit, and the results are plotted $1/C^2$ against potential versus RHE.

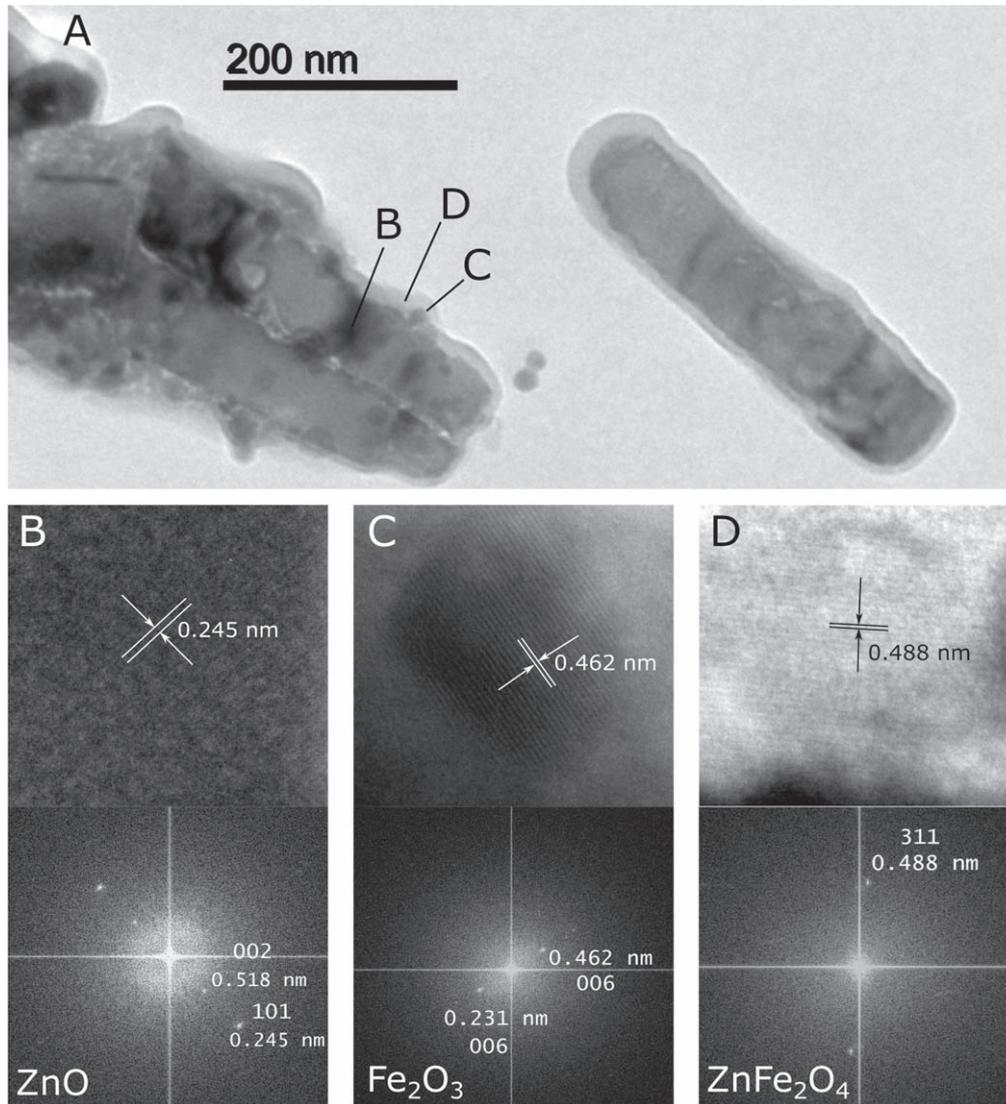


Figure 4. (A) HRTEM micrograph of the sample at low magnification with specific sites labelled. (B) The magnified image of the NR showing (top) atomic real space and (bottom) the FFT of the image. (C) The nanoparticle magnified image with atomic spacing (top) and FFT (bottom). (D) The thin film coating of the NR magnified, atomic spacing (top) and FFT (bottom).

These plots in figure 5(B) provide useful physical information such as dopant density N_D , and flat band potential, V_{FB} , corresponding to the Fermi level of the material. The M-S plot of pristine ZnO can be found in figure S5(C).

The determined M-S values can be found in table S1 alongside their detailed calculation in the supporting information. Y doping leads to a significant increase in dopant density and a 0.2 V negative shift in V_{FB} , confirming the conductivity increase from doping. The carrier density of ZnO is nearly doubled with Y doping from $7.5 \times 10^{25} \text{ m}^{-3}$ (ZnO) to $1.35 \times 10^{26} \text{ m}^{-3}$ (YZnO), in agreement with our previous work [37]. This confirms the electron highway function of the conductive YZnO NRs which can efficiently transport charge to the FTO. The pure α -Fe₂O₃, conversely has a more positive value of V_{FB} alongside a lower n-type doping of $5.08 \times 10^{25} \text{ m}^{-3}$.

As no pure ZnFe₂O₄ sample was synthesised in this work, the precise band positions could not be determined.

However, it was reported to have a V_{FB} of $0.83 V_{RHE}$ with an accompanying N_D value of $3.63 \times 10^{22} \text{ m}^{-3}$ [47]. These values are crucial as they determine the nature of the n-n junction. At the interface, the higher n-type doped sample will donate electrons forming a space charge region, equalising E_F across the junction [48]. Therefore, in this case, YZnO will donate electrons to the contacting layer of ZnFe₂O₄ causing a positive potential shift in E_F in the former, and negative in the latter. By extension, the same effect will occur from Fe₂O₃ to ZnFe₂O₄, shifting E_F to be more positive within hematite.

XPS was also used to determine VB position by scanning for the valence edge from 0 to 10 eV binding energy, followed by extrapolating linear regions to the base line intercept. Once the VB is determined, the conduction band edge was calculated using the corresponding E_g . The results for YZnO, Fe₂O₃ and the composite material can be found in figure 5(C), whereas the VB of undoped ZnO sample is displayed in figure S5(D). The VB of ZnO and YZnO were

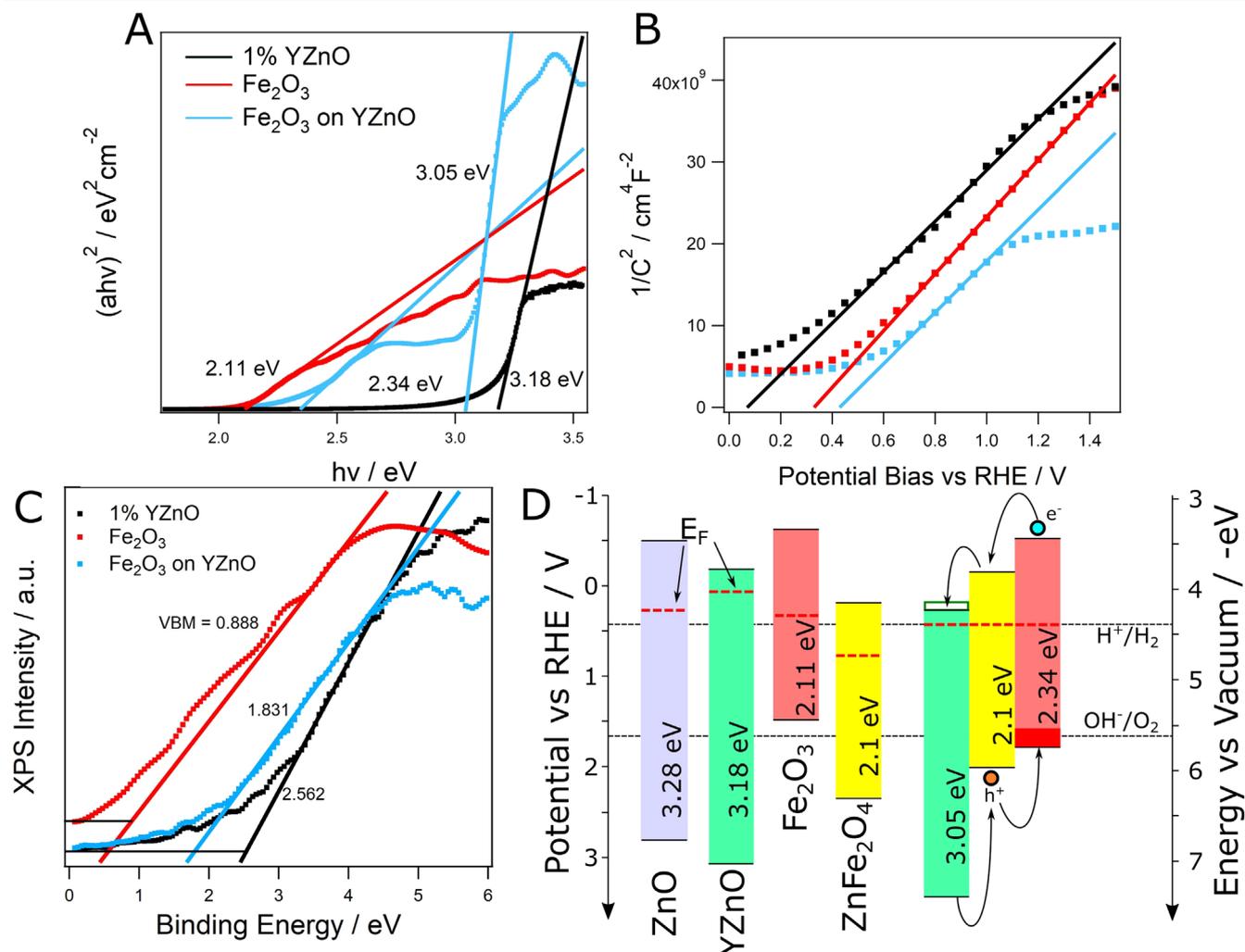


Figure 5. (A) Shows the Tauc plots calculated from UV-vis absorbance data used to calculate the direct bandgaps of the samples. Mott-Schottky plots of the uncoated Y doped sample, the pure Fe₂O₃ sample and the optimised 40 μA coated sample are displayed in (B). (C) Shows the XPS valence band maxima survey of the samples. The calculated Fermi level, conduction band and valence band positions of the semiconductors found in this study are shown with respect to the redox potentials of water in (D).

measured to be 2.182 and 2.562 eV respectively, in good agreement with literature [17]. The value for pristine Fe₂O₃ was determined to be more positive, at 0.888 eV, similar to the value of 1.4 eV determined by Li *et al* [49]. Finally the hematite coated YZnO NRs yielded a value of 1.831 eV. As a technique XPS is only surface sensitive, as the path length of electrons excited within the bulk is typically around a few nm due to rapid reabsorption [50]. Therefore, based on the HRTEM micrographs indicating homogenous coverage of ZnFe₂O₄, it can be assumed that the junction VB maximum is due to this material, bolstered by its close match with previously reported values [46]. Using this information, the full electronic structure of the triple heterojunction can be mapped out, displayed in figure 5(D). By aligning the Fermi levels, it becomes clear that the triple junction has significant improved charge separation, which could enhance the efficiency for solar water splitting. Firstly, due to their significantly difference in E_g values, both UV and visible light will be utilised to generate holes. Secondly, the VB positions of the triple junction gives suitable alignment for rapid hole transfer from

the core YZnO NRs through the ZnFe₂O₄ thin film to the surface particulate Fe₂O₃. Thirdly, the conduction band positions allow the electrons to cascade into the YZnO cores, which, in turn, shuttle electrons quickly to the counter electrode with high conductivity. This is essential for removing charge before recombination with holes and consequentially enable high rate evolution of hydrogen at the platinum surface. This mechanism is confirmed by E_F /band shifts predicted by dopant density values, anticipating high performance solar water splitting.

The impact of the designed novel NR structure can be seen clearly in the dramatic enhancement in PEC water splitting, figure 6. Firstly, the effects of Fe₂O₃ coating and the Y-doping in ZnO are presented in figure 6(A). With the 40 $\mu\text{A cm}^{-2}$ Fe deposition rate, the photocurrent increased by 44% over the uncoated, undoped ZnO, from 0.66 to 0.83 mA cm^{-2} at 1.23 V_{RHE} . This is due to the benefits of the n-n triple junction previously described, alongside the absorption of visible light photons due to the low band gap of Fe₂O₃ and ZnFe₂O₄. Using the additional beneficial transport

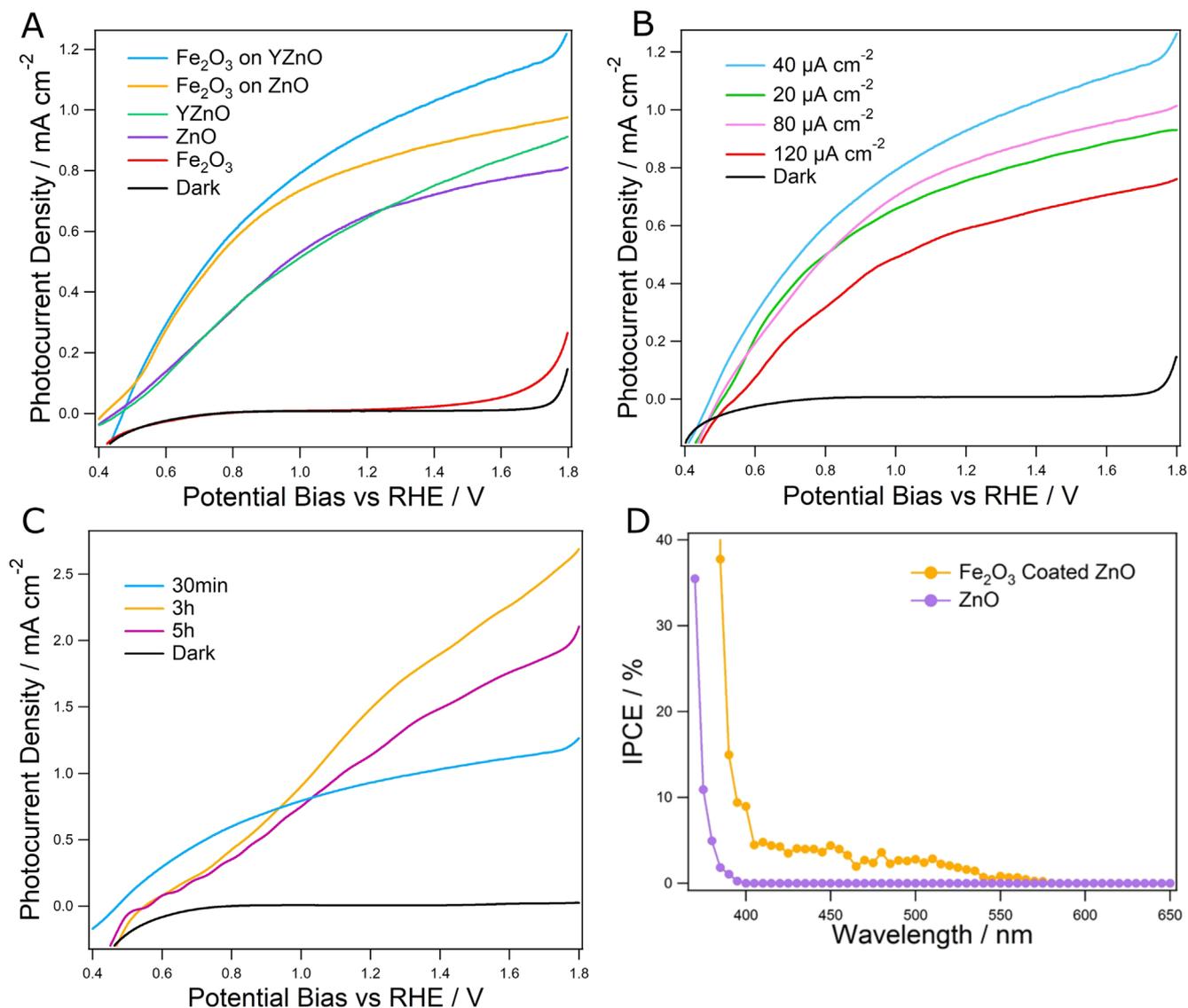


Figure 6. A shows the general comparison of doped versus undoped samples, with and without coating, the performance optimisation from the various electrodeposition currents is shown in (B). (C) Shows the annealing duration optimisation, showing further enhancement, and finally (D) shows the incident photon to current efficiency.

properties of Y doping alongside coating, the performance increases further to 0.95 mA cm^{-2} . Despite high natural donor defect density in the microwave synthesised sample [36], the conductivity gains by yttrium doping allow the same $40 \mu\text{A cm}^{-2}$ coating to yield 14% higher photocurrent at $1.23 \text{ V}_{\text{RHE}}$ [37]. This is due to more efficient transportation of charge carriers from the solid/electrolyte interface by YZnO. The pure Fe₂O₃ sample shows critically low water splitting due to the high recombination and likely higher charge transfer resistance R_{CT} , managing $13 \mu\text{A cm}^{-2}$ at $1.23 \text{ V}_{\text{RHE}}$.

The performance is highly sensitive to the deposition current density as shown in figure 6(B), with the lightest coating, $20 \mu\text{A cm}^{-2}$, only slightly outperforming the uncoated YZnO NRs. This is due to the lack of extra light absorption with such a thin layer of Fe₂O₃. Conversely the $120 \mu\text{A cm}^{-2}$ sample sees a large performance drop, achieving a lower photocurrent than the uncoated sample. The reasons for this are twofold, firstly the unfavourable

morphology measured by SEM indicates a loss in surface area, restricting the access to electrolyte. Secondly, electron-hole recombination stifles the performance of thick Fe₂O₃ film, due to the short minority carrier path length in $\alpha\text{-Fe}_2\text{O}_3$ [42]. This is evidenced by the largest charge transfer resistance, R_{CT} , indicated by the greatest arc radius in its Nyquist plot, figures S6(A) and (B). The values of R_{CT} were calculated using a simple Randle's circuit and plotted against deposition current in figure S6(C). A large R_{CT} is due to a greater resistive barrier for charge to overcome to enter the electrolyte, caused by the poor charge transportation of Fe₂O₃. The photoluminescence spectra in figure S6(D), directly measure the outgoing photons when recombination occurs. Once the photoabsorbing layer becomes sufficiently thick, the photo-excited electrons are unable to reach the YZnO resulting in increased charge recombination. Therefore an increase in PL intensity is seen with deposition current.

The $40 \mu\text{A cm}^{-2}$ samples were further optimised by different durations of annealing. Longer periods of air annealing can be used to greatly improve the crystal quality of hematite [33], reducing the electron hole recombination rates. The results are displayed in figure 6(C), displaying a dramatic further enhancement in photocurrent density for the optimised duration of 3 h at 550°C , up to 1.59 mA cm^{-2} at $1.23 \text{ V}_{\text{RHE}}$. This 67% enhancement over the sample annealed for 30 min represents a significant improvement, and a 2.4 times increase over the uncoated nanorods. Stepped light/dark LSV was also performed, figures S7(A) and (B), which shows negligible dark currents. Furthermore, the optimised anode performances were stable in solution at a fixed potential of $1.23 \text{ V}_{\text{RHE}}$, shown in figure S7(C). There is no significant decay of photocurrent over time.

The optimised performance catapults this work to the frontier of solar water splitting, achieving nearly the highest photocurrent ZnO/iron oxide photoanode in literature. To the authors knowledge this is the most efficient solar water splitting device utilising a ZnO/Fe₂O₃ junction at $1.23 \text{ V}_{\text{RHE}}$. Typically these devices achieve negligible photocurrent in this potential region, requiring larger potential bias to promote water oxidation [51–53]. The most successful device constructed by Hsu *et al* generated 1.25 mA cm^{-2} at $1.23 \text{ V}_{\text{RHE}}$ through spin coating Fe₂O₃ on pristine ZnO NRs [18]. More success has been achieved by the coating of ZnFe₂O₄ on ZnO surfaces, with typical photocurrents ranging from 0.05 to 0.57 mA cm^{-2} [54, 55]. The great achievement of 1.72 mA cm^{-2} by Xu *et al* was achieved through coating Al doped ZnO, on NRs [40]. This implies further optimising the ZnO NRs with doping may improve our samples further.

Finally, incident photon to current conversion efficiency can be found in figure 6(D) elegantly displaying the visible light sensitisation of the final sample. This data shows a significant efficiency increase at photon energies higher than 529 nm (2.34 eV) due to the Fe₂O₃ absorption onset, increasing to ~5% at 450 nm. Optical power density versus wavelength is displayed in figure S8. Some photocurrent is generated at wavelengths as long as 575 nm, likely due to the presence of the 8 nm layer of ZnFe₂O₄ on the rods, injecting electrons at even lower energies. This is in contrast to the uncoated ZnO sample which remained flat at wavelengths longer than 400 nm. At this wavelength the coated sample experiences a stark increase in efficiency again, due to the effective band gap reduction of ZnO, rising to 10% at 395 nm. All this confirms the success of the triple junction, able to absorb visible light photons and transfer photoexcited electrons to yttrium doped ZnO highways, for greatly improved solar water splitting.

4. Conclusion

In conclusion a novel electrodeposition method was developed and used to build a ZnO/Fe₂O₃/ZnFe₂O₄ triple junction photoanode, based on yttrium doped ZnO NRs. The new coating method allowed fine control the morphology of hematite grown on the surface of the nanorods, as evidenced

by SEM, XRD and TEM. Meanwhile the presence of ZnFe₂O₄ was also confirmed, forming a thin layer coating on the NRs. This had the effect of sensitising the ZnO to visible light, as evidenced through UV–vis absorption spectroscopy and IPCE, utilising a favourable junction cascade for electron transfer to the ZnO and hole transfer to the solution. This effectively reduced the charge recombination effects in $\alpha\text{-Fe}_2\text{O}_3$ as measured by EIS and PL spectroscopy, leading to an optimised coating thickness at a current density of $40 \mu\text{A cm}^{-2}$. The yttrium doping of the NRs yielded a 14% enhancement over the pristine ZnO NRs, confirming the effects of conductive ZnO in addition to its photon trapping and light waveguiding effects. Optimising hematite crystallinity by control the annealing process led to a champion photocurrent of 1.59 mA cm^{-2} at $1.23 \text{ V}_{\text{RHE}}$, representing a 2.4 times enhancement over the uncoated ZnO NRs. This work represents an important advancement in the application of nanostructured junctions to PEC water splitting.

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